

Supporting information

Rational Design of $Ti_3C_2T_x$ MXene Inks for Conductive, Transparent Films

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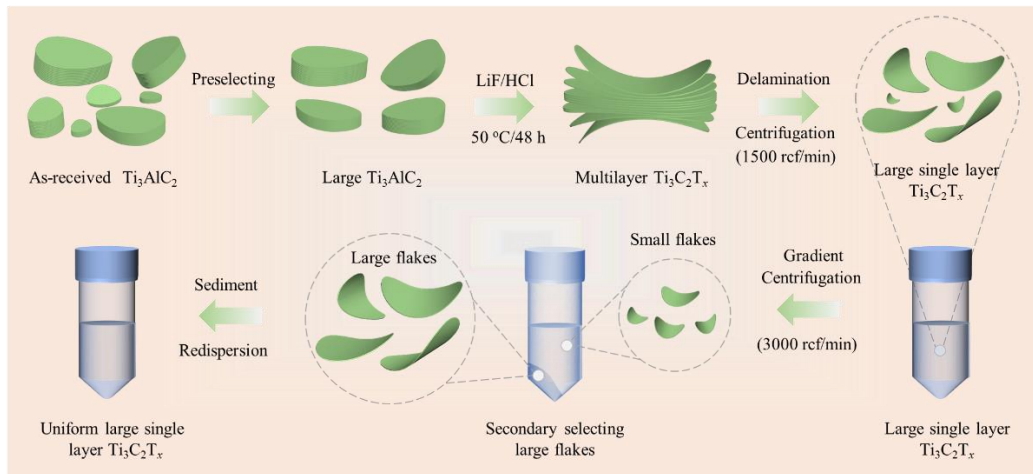
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Scheme S1 Schematic illustration of the synthesis process of ultralarge sized $\text{Ti}_3\text{C}_2\text{T}_x$ flakes from the as-received Ti_3AlC_2 phase.

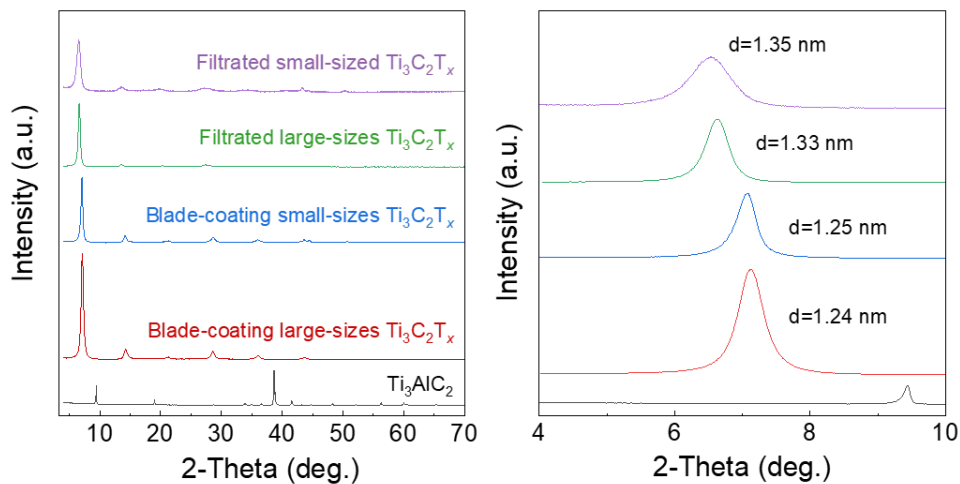


Figure S1 XRD patterns of Ti_3AlC_2 , opaque $\text{Ti}_3\text{C}_2\text{T}_x$ films with large-sizes and small-sizes by vacuum-assisted filtration and blade coating.

$\text{Ti}_3\text{C}_2\text{T}_x$ films prepared by blade coating have a smaller interlayer spacing than those of filtrated films. Their interlayer spacing is 1.24 nm (blade-coating large-sized $\text{Ti}_3\text{C}_2\text{T}_x$), 1.25 nm (blade-coating small-sized $\text{Ti}_3\text{C}_2\text{T}_x$), 1.33 nm (filtrated large-sized $\text{Ti}_3\text{C}_2\text{T}_x$), 1.35 nm (filtrated large-sizes $\text{Ti}_3\text{C}_2\text{T}_x$), respectively.

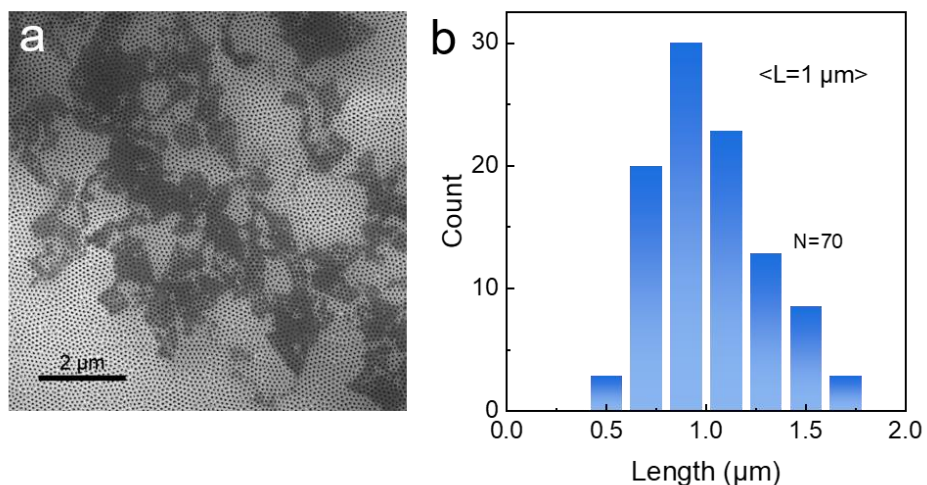


Figure S2 **a** SEM image of small-sized $\text{Ti}_3\text{C}_2\text{T}_x$ flakes on anodic aluminum oxide (AAO). **b** Histogram of the small-sized $\text{Ti}_3\text{C}_2\text{T}_x$ flakes determined by statistical analysis.

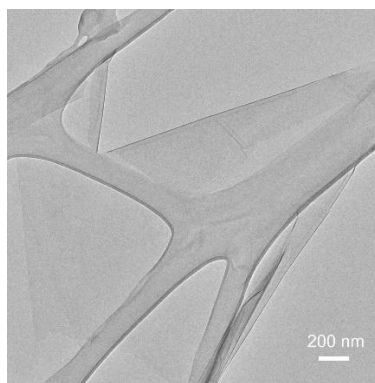


Figure S3 TEM image of **a** $\text{Ti}_3\text{C}_2\text{T}_x$ flake

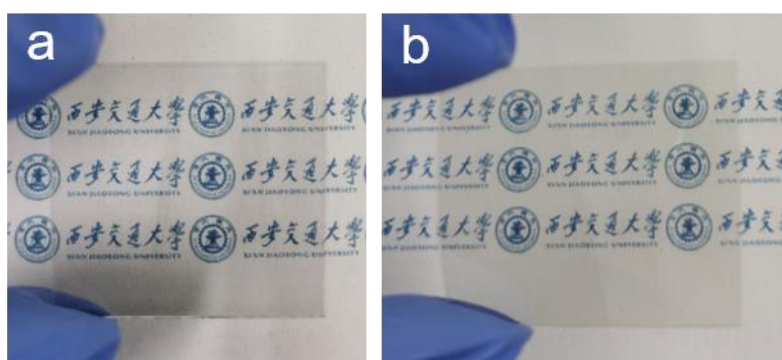


Figure S4 Digital photograph of $\text{Ti}_3\text{C}_2\text{T}_x$ films from large-sizes flakes on glass (**a**, $T=87\%$), on PET (**b**, $T=91\%$).

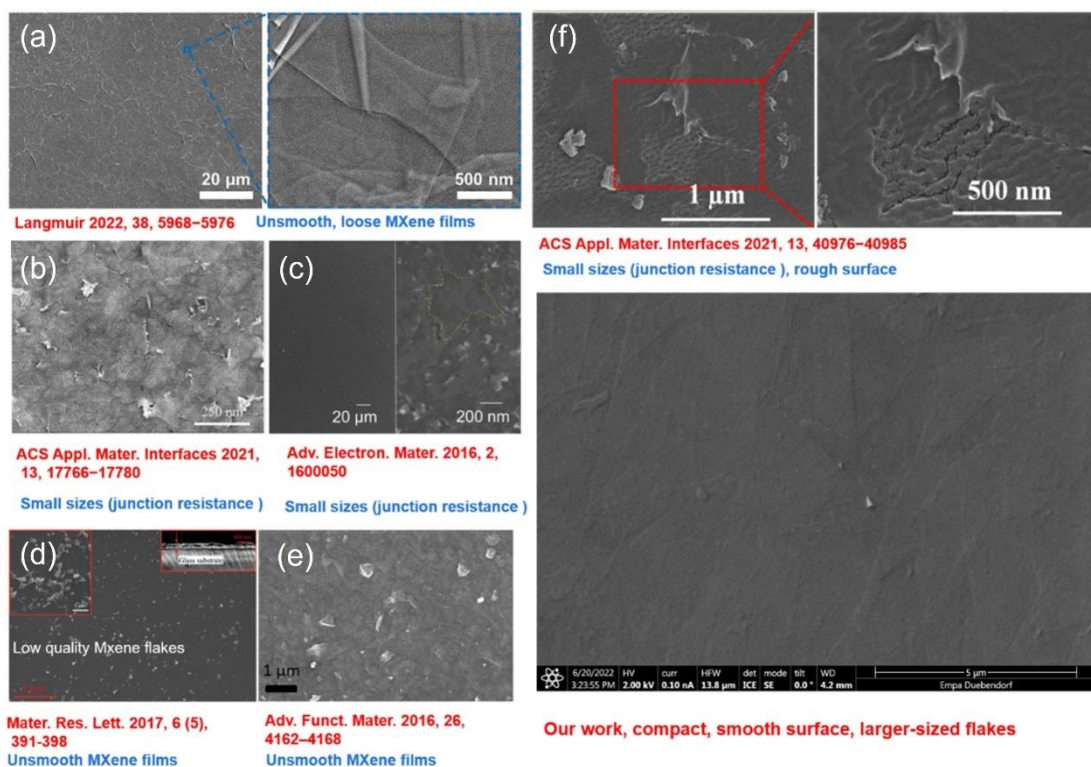


Figure S5 Comparison of SEM images from previously published works with our transparent MXene film. **a** Reproduced with permission.¹ Copyright 2022, American Chemical Society. **b** Reproduced with permission.² Copyright 2021, American Chemical Society. **c** Reproduced with permission.³ Copyright 2016, John Wiley and Sons. **d** Reproduced with permission.⁴ Copyright 2017, Taylor & Francis Group. **e** Reproduced with permission.⁵ Copyright 2016, John Wiley and Sons. **f** Reproduced with permission.⁶ Copyright 2021, American Chemical Society.

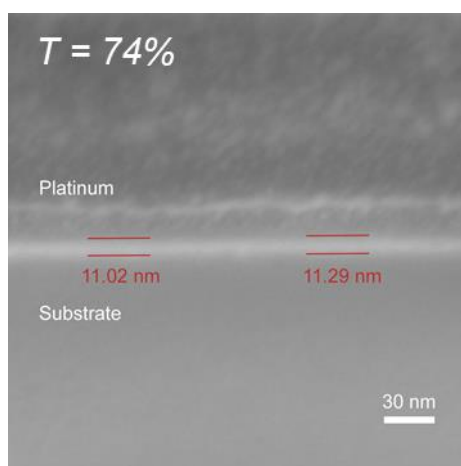


Figure S6 Cross-sectional FIB-SEM image of a blade coated $Ti_3C_2T_x$ film. ($T=74\%$).

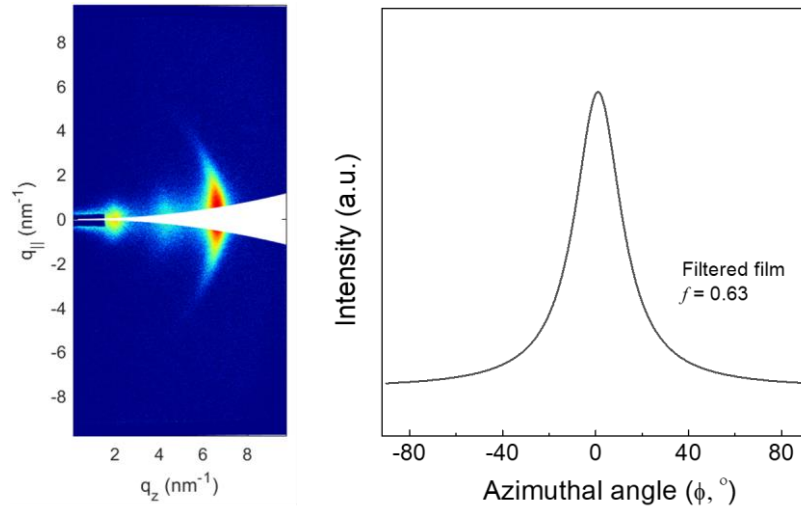


Figure S7 GISAXS measurement of a filtered film ($\sim 1 \mu\text{m}$). GISAXS detector image showing the (002) peak over q_z . Lorentzian fit of the azimuthal profile for the (002) peak used to determine Herman's degree of orientation.

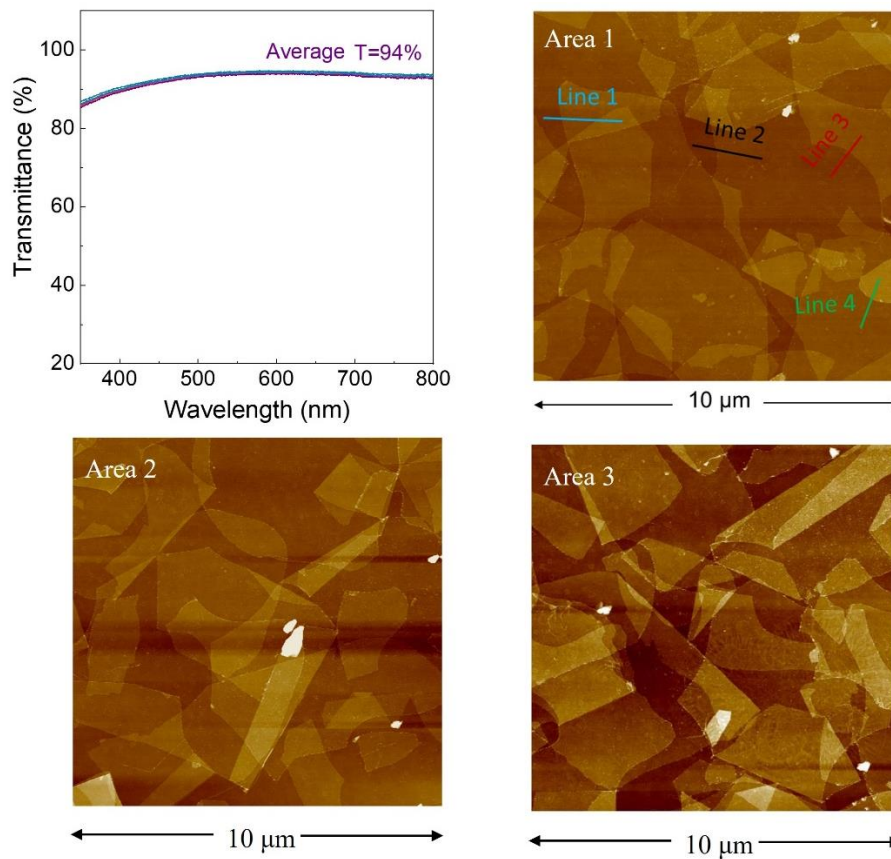


Figure S8 The average transmittance of TCEs and the surface topography of different regions were measured by AFM.

Methods for calculating the number of layers of high transparency films ($T=94\%$), according to the area percentage of the different layers $Ti_3C_2T_x$ flakes in the $10\times 10\ \mu m$ area (for the area 1 image). Areas comprising different numbers of layers in Figure 3f are shown with different colors.

Table S1 Calculation of thickness of high transparency film ($T=94\%$).

	Pixel	Percentage (%)	Percentage (%)
Single layer	371 691	37.5%	35.7%
Double layers	495 421	50.0%	47.6%
Triple layers	132 210	13.4%	12.7%
Quadruple layers	15 827	1.6%	1.5%
Substrate (not covered)	25 060	2.5%	2.4%
Actual image pixel	990 024	105%	
Statistical pixel totals	1 040 209		99.9%

Area 1, image pixels: $996\times 994=990\ 024$

The actual number of pixels counted according to different colors: 1 040 209

Thanks to the pixels at different color boundaries may be counted multiple times, the actual count is slightly higher than the number of pixels in the image.

Method 1:

Single layer: $371\ 691/990\ 024 = 37.5\%$

Double layers: $495\ 421/990\ 024 = 50.0\%$

Triple layers: $132\ 210/990\ 024 = 13.4\%$

Quadruple layers: $15\ 827/990\ 024 = 1.6\%$

Substrate: $25\ 060/990\ 024 = 2.5\%$

Layers calculation: $1\times 0.375+2\times 0.5+3\times 0.134+4\times 0.016=1.84$

Percentage of coverage: $100\%-2.5\%=97.5\%$

Method 2:

Single layer: $371\ 691/1\ 040\ 209 = 35.7\%$

Double layers: $495\ 421/1\ 040\ 209 = 47.6\%$

Triple layers: $132\ 210/1\ 040\ 209 = 12.7\%$

Quadruple layers: $15\ 827/1\ 040\ 209 = 1.5\%$

Substrate: $25\ 060/1\ 040\ 209 = 2.4\%$

Layers calculation: $1\times 0.357+2\times 0.476+3\times 0.127+4\times 0.015=1.75$

Percentage of coverage: $100\%-2.4\%=97.6\%$

Thus, the thickness of the TCE ($T=94\%$) is 1.8 layers and the coverage is about 98%.

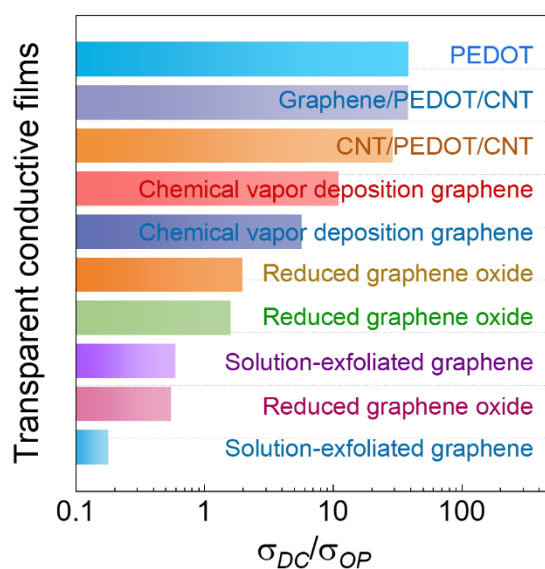


Figure S9 Comparison of σ_{DC}/σ_{op} (FOM_e) of various transparent conductive films, detailed values are presented in Table S2.

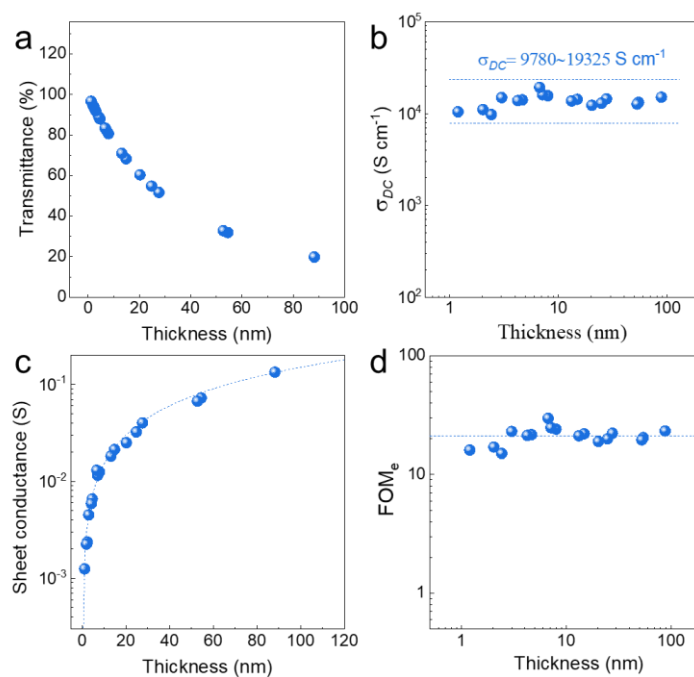


Figure S10 Relationship between $Ti_3C_2T_x$ films thickness and optoelectronic properties. **a** Transmittance, **b** DC conductivity, **c** sheet conductance, **d** Ratio of DC conductivity to optical conductivity.

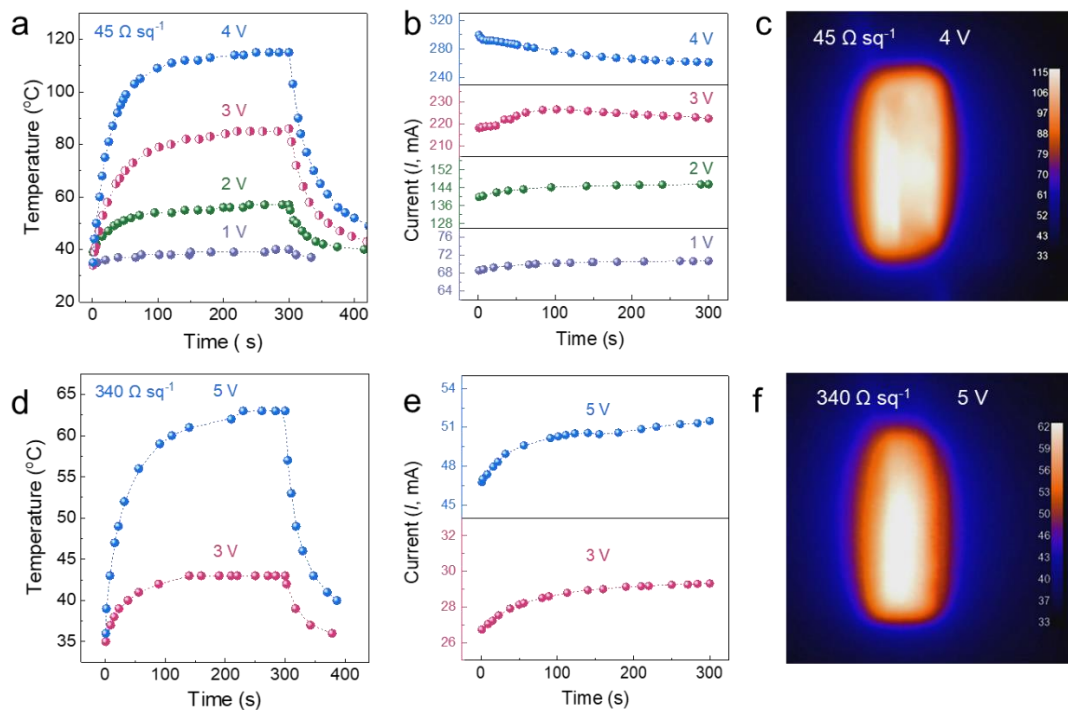


Figure S11 Electrothermal properties of $\text{Ti}_3\text{C}_2\text{T}_x$ films. The time-varying surface temperature of the $\text{Ti}_3\text{C}_2\text{T}_x$ films with $45 \Omega \text{ sq}^{-1}$ **a)** and $340 \Omega \text{ sq}^{-1}$ **d)** for different applied voltages. **b), e)** The corresponding current values as a function of time. Infrared radiation (IR) images of the transparent $\text{Ti}_3\text{C}_2\text{T}_x$ films with $45 \Omega \text{ sq}^{-1}$ **c)** and $340 \Omega \text{ sq}^{-1}$ **f)**.

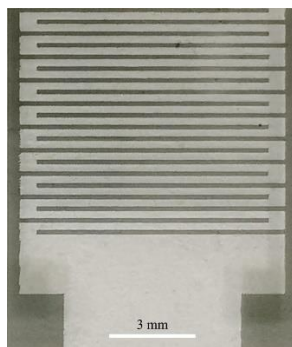


Figure S12 Digital photograph of $\text{Ti}_3\text{C}_2\text{T}_x$ -based symmetric micro-supercapacitors

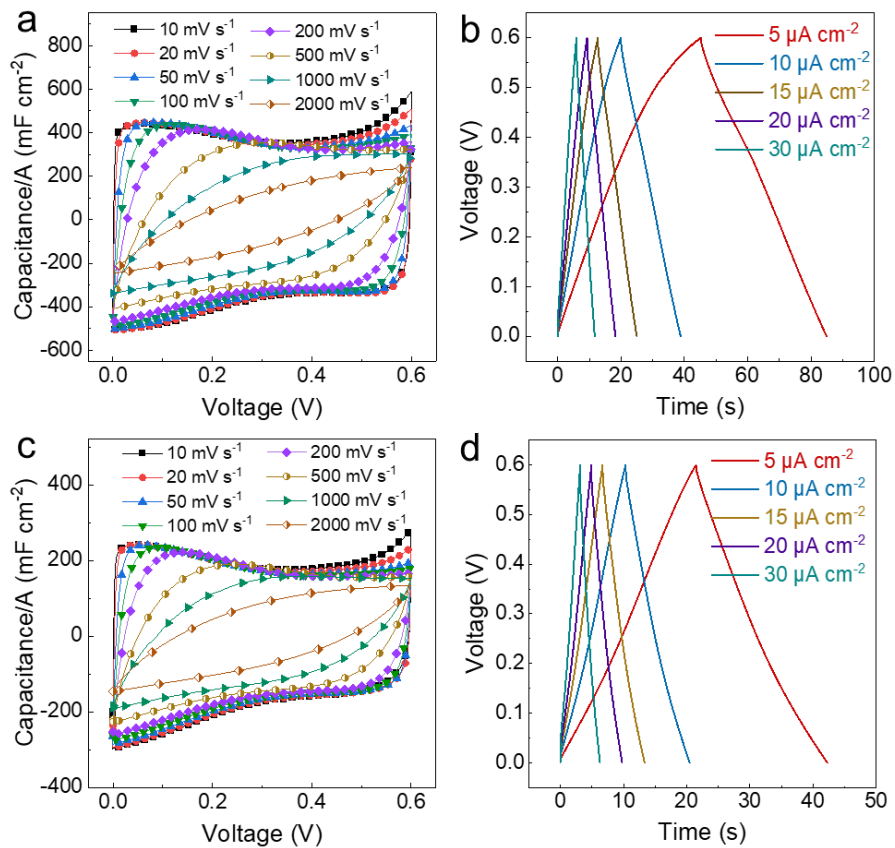


Figure S13 Electrochemical characterization of $\text{Ti}_3\text{C}_2\text{T}_x$ films. Normalized CV curves at various scan rates of **a)** $T=49\%$, **c)** $T=61\%$, and GCD curves at different current densities of **b)** $T=49\%$, **d)** $T=61\%$.

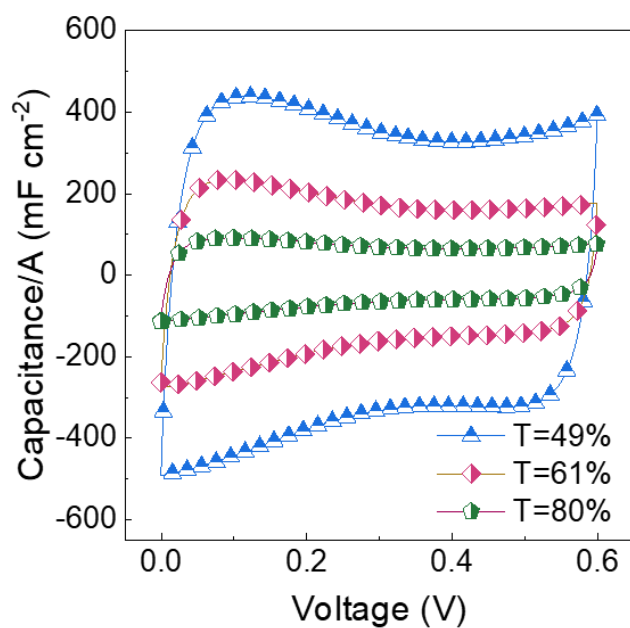


Figure S14 CV curves with different transparency at 100 mV s^{-1} .

Table S2 of Figure 3b

Samples	Sizes	Manufacturing technique	Transmittance ($T_{550\text{ nm}}$, %)	Sheet resistance ($\Omega\text{ sq}^{-1}$)	FoM _e	Ref.
Ti ₃ C ₂ T _x	100~300 nm	Inkjet-printing	24	1500	0.12	2
Ti ₃ C ₂ T _x	~500 nm	Spray-coating	~51 ~81	~625 ~8160	0.51	3
Ti ₃ C ₂ T _x	~80 nm	Spin-coating	72 83 90 94	2010 3850 11870 23660	2	7
Ti ₃ C ₂ T _x	~110 nm	Spin-coating	~72 ~87	~440 ~8900	3.1	8
Ti ₂ CT _x	~1 μm	Spin-coating	65 80 86 96	128 507 1100 6440	5	4
V ₂ CT _x	0.5~1 μm	Spin-coating	~50	~67	6.5	9
Ti ₃ C ₂ T _x	—	Spin-coating	86	330	7.3	5
Ti ₃ C ₂ T _x	~0.5 μm	Dip-coating	~86	~375	9	10
Ti ₃ C ₂ T _x	~1.4 μm	Dip-coating	~88	~600	14	
Ti ₃ C ₂ T _x	~1.4 μm / Optimized	Dip-coating	~89 ~92	~320 ~1870	17	
Ti ₃ C ₂ T _x	1~2 μm	Dip-coating	51 94	40 4300	14	11
Ti ₃ C ₂ T _x	~3.2 μm	Spin-coating	86 90 94	200 532 1031	15	12
Ti ₃ C ₂ T _x	12.2 μm	Blade-coating	20	7.5	21	This work
			60	40		
			81	80		
			89	170		
			94	423		

Table S3 of Figure S9

Samples	FoM _e	Ref.
PEDOT	39	13
Graphene/PEDOT/CNT	38.6	14
CNT/PEDOT/CNT	29.18	15
CVD-graphene	11.13	16
CVD-graphene	5.7	17
Reduced graphene oxide	2	18
Reduced graphene oxide	1.6	19
Solution-exfoliate graphene	0.6	20

Reduced graphene oxide	0.55	21
Solution-exfoliated graphene	0.18	22

Table S4 of Figure 4c

Samples	Average electronic conductivity (S cm ⁻¹)	Ref.
Reduced graphene oxide	550	23
Reduced graphene oxide	1425	24
Ti ₃ C ₂ T _x	3092	8
Ti ₂ CT _x	5250	4
Ti ₃ C ₂ T _x	6500	5
Ti ₃ C ₂ T _x	7450	12
Ti ₃ C ₂ T _x	7530	10
Ti₃C₂T_x	15000	This work

Table S5 of Figure 6g

Samples	Transmittance (T _{550 nm} ,%)	Capacitance (μF cm ⁻²)	Ref.
Graphene Q-dot	93	9.1	25
Graphene networks	84	4.2	26
Wrinkled graphene	60	5.8	27
Graphene film	67	12.4	28
Ti ₃ C ₂ T _x	88	19	11
	38	283	
Ti ₃ C ₂ T _x	81	870	12
Ti ₃ C ₂ T _x	73	192	2
Ti₃C₂T_x	49	383.16	This work
	61	189.5	
	80	75.3	

Table S6 of Figure 6h

Samples	Transmittance (T _{550 nm} , %)	Power density ($\mu\text{W cm}^{-2}$)	Energy density($\mu\text{Wh cm}^{-2}$)	Ref.
Graphene film	67	70	0.00047	28
Ti ₃ C ₂ T _x	88	0.0188	0.00163	11
	38	1.3	0.01	
Ti ₃ C ₂ T _x	73	0.077	0.0043	2
Ti ₃ C ₂ T _x	49	1.1496	0.01916	This work
		2.28	0.019	
		5.526	0.01842	
		10.608	0.01768	
		19.836	0.01653	
	61	0.5682	0.00947	
		1.1244	0.00937	
		2.733	0.00911	
		5.244	0.00874	
		9.792	0.00816	
	80	0.2256	0.00376	
		0.4512	0.00376	
		1.098	0.00366	
		2.118	0.00353	
		3.948	0.00329	

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